

SANYO**CPH6104/CPH6204****High-Current Switching Applications****Applications**

- DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes.

Features

- Adoption of FBET, MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package permitting applied sets to be made small and slim (0.9mm).
- High allowable power dissipation.

(): CPH6104

Specifications**Absolute Maximum Ratings** at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)15	V
Collector-to-Emitter Voltage	V_{CE0}		(-)15	V
Emitter-to-Base Voltage	V_{EB0}		(-)5	V
Collector Current	I_C		(-)1.5	A
Collector Current (Pulse)	I_{CP}		(-)3	A
Base Current	I_B		(-)200	mA
Collector Dissipation	P_C	Mounted on a ceramic board (600mm \times 0.8mm)	1.3	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)12\text{V}, I_E = 0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{V}, I_C = 0$			(-)100	nA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2\text{V}, I_C = (-)50\text{mA}$	200		560	
	h_{FE2}	$V_{CE} = (-)2\text{V}, I_C = (-)800\text{mA}$	80			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)2\text{V}, I_C = (-)50\text{mA}$		(300)		MHz
				200		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10\text{V}, f = 1\text{MHz}$		(15)10		pF

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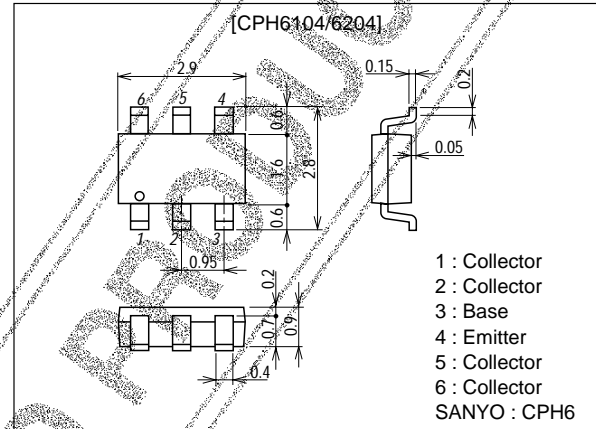
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Package Dimensions

unit:mm

2146A



1 : Collector
2 : Collector
3 : Base
4 : Emitter
5 : Collector
6 : Collector
SANYO : CPH6

SANYO Electric Co.,Ltd. Semiconductor Company

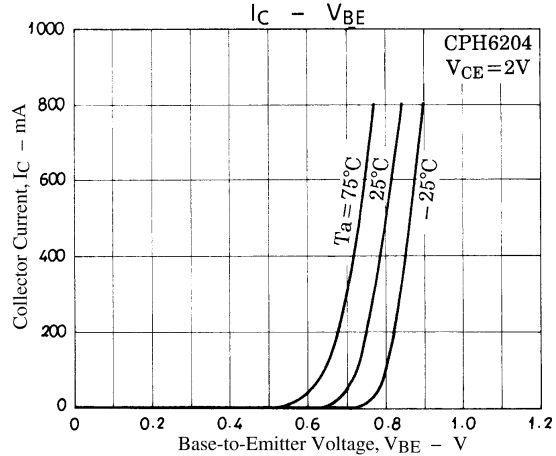
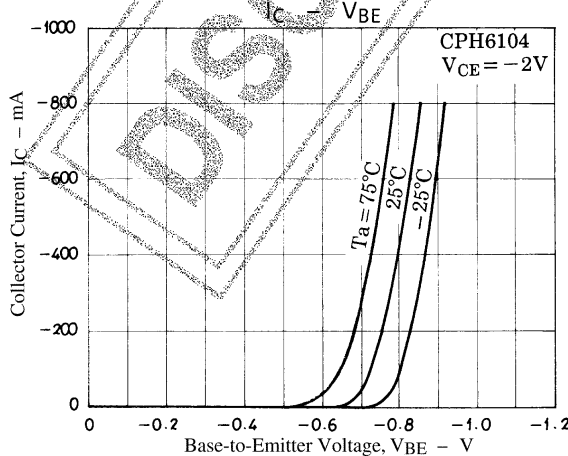
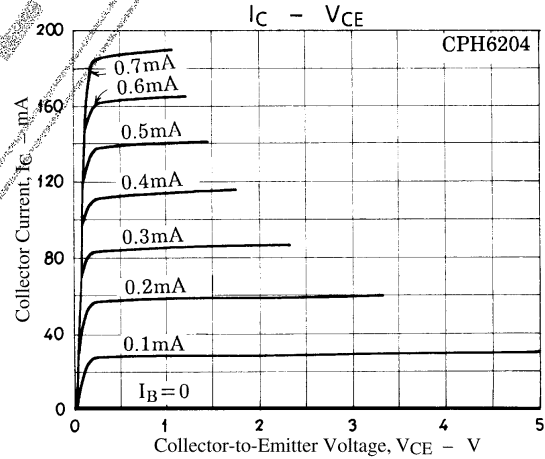
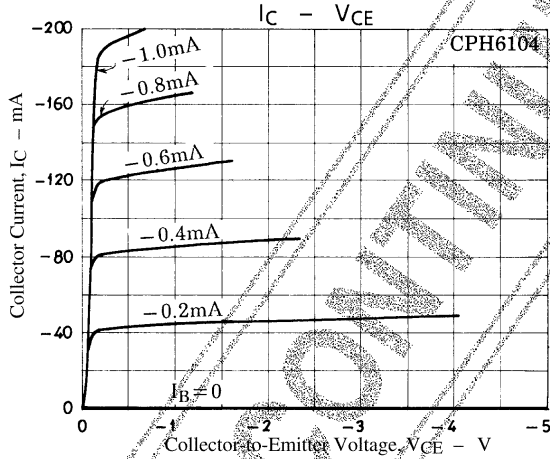
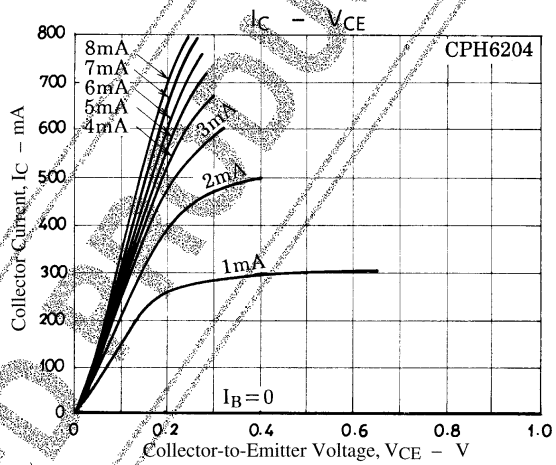
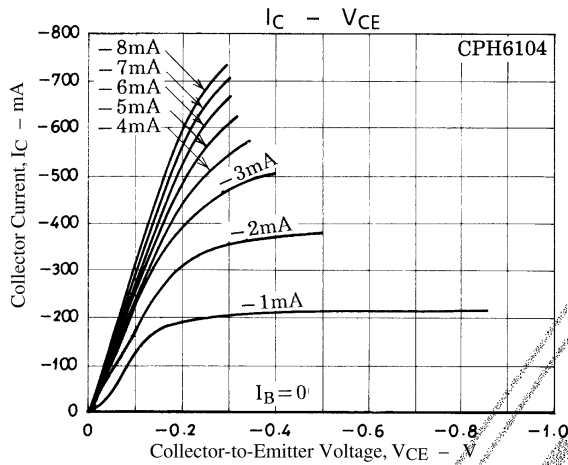
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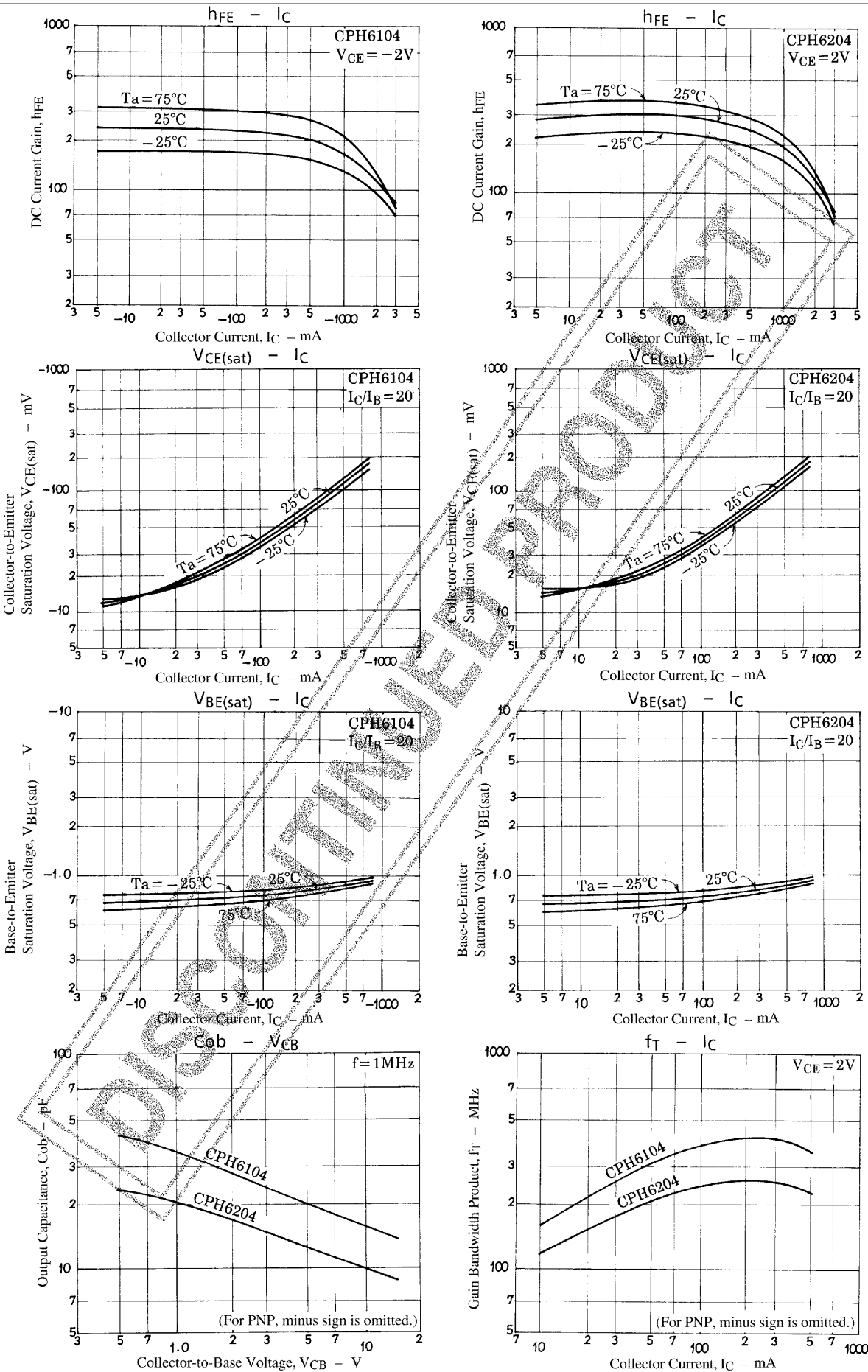
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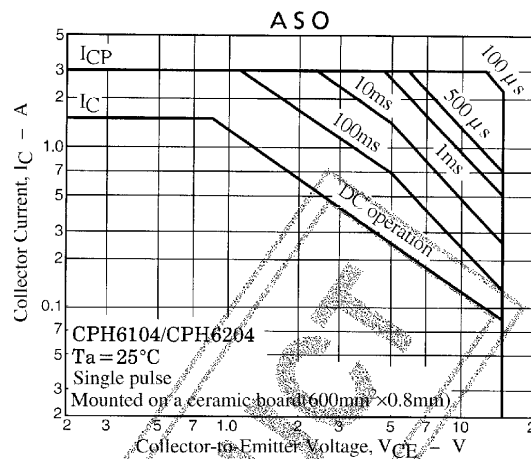
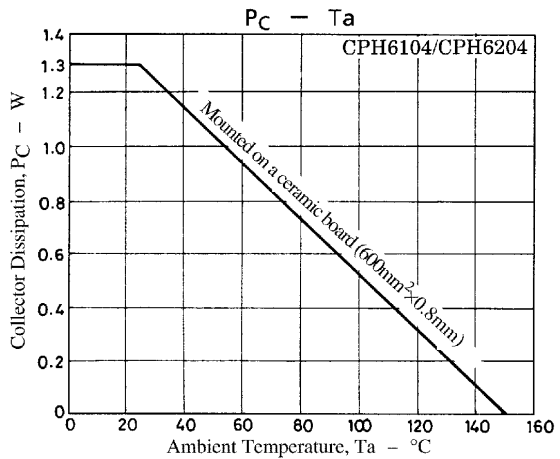
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=(-)5mA, I_B=(-)0.5mA$		(-10)	(-25)	V
	$V_{CE(sat)2}$	$I_C=(-)500mA, I_B=(-)25mA$		(-120)	(-240)	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)500mA, I_B=(-)25mA$		(-0.9)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$		(-15)		V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$		(-15)		V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$		(-5)		V



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